

Home Search Collections Journals About Contact us My IOPscience

The mutual influence of chemisorption and surface segregation: calculation of the chemisorption energy of O or CO on Ni-Cu alloy

This article has been downloaded from IOPscience. Please scroll down to see the full text article. 1992 J. Phys.: Condens. Matter 4 L529 (http://iopscience.iop.org/0953-8984/4/40/006)

View the table of contents for this issue, or go to the journal homepage for more

Download details: IP Address: 171.66.16.96 The article was downloaded on 11/05/2010 at 00:37

Please note that terms and conditions apply.

LETTER TO THE EDITOR

The mutual influence of chemisorption and surface segregation: calculation of the chemisorption energy of O or CO on Ni-Cu alloy

Hui Zhang

Department of Physics, Shenyang Normal College, Shenyang 110031, People's Republic of China

Received 27 July 1992

Abstract. The Green's function method and the chemisorption theory of Einstein and Schrieffer are used to calculate the chemisorption energy of O or CO on a Ni-Cu disordered binary alloy surface using the average *T*-matrix approximation. The change of surface segregation due to chemisorption is investigated in detail. From the chemisorption point of view, the behaviour of O resembles that of CO to a certain extent. The calculated results show that the chemisorption of O/Ni-Cu and CO/Ni-Cu systems can all constrain surface segregation, resulting in more stable chemisorption.

In our previous paper [1], we studied the chemisorption of the CO/Ni-Cu system using the coherent-potential approximation (CPA) and obtained some important conclusions: that the chemisorption of the system can change surface concentration, constrain surface segregation and make the chemisorption energy decrease. In this letter, we employ the average T-matrix approximation (ATA) and the Green's function (GF) method to study further the chemisorption properties of O/Ni-Cu and CO/Ni-Cu systems. The purpose of the present work is to emphasize the mutual influence of chemisorption and surface segregation. Within the one-dimensional tight-binding approximation, the chemisorption system consists of the effective adsorbate [1] interacting with a semi-infinite, monatomic chain of Ni-Cu disordered binary alloy (DBA). The model of a substitutional DBA developed by Ueba *et al* [2] is adopted. The virtual-crystal Hamiltonian for the substrate is then

$$H_{\mathbf{v}} = \sum_{i=1}^{\infty} \left\{ \alpha_i |i\rangle \langle i| - T(|i\rangle \langle i+1| + |i+1\rangle \langle i|) \right\}.$$

$$\tag{1}$$

In (1), the effective bond strength -T between nearest-neighbour atoms is concerned with the bulk concentration X_b of the A component. On confining surface segregation to the first (surface) layer, the virtual-crystal electronic energy [1] at atom *i* is

$$\alpha_{i} = \begin{cases} X_{b}\Delta + \epsilon_{B} & i > 1\\ X_{s}\Delta + \epsilon_{B} & i = 1, \text{ before chemisorption} \\ X_{c}\Delta + \epsilon_{B} & i = 1, \text{ after chemisorption} \end{cases}$$
(2)

where $\Delta = \epsilon_A - \epsilon_B$, $\epsilon_A (\epsilon_B)$ is the electronic energy of an A (B) atom and $X_s (X_c)$ is the surface concentration of the A component at the site 1 of the DBA before (after) chemisorption.

0953-8984/92/400529+04\$04.50 © 1992 IOP Publishing Ltd

Within the ATA, the self-energy [2,3] associated with the *i*th atomic site is introduced as

$$\xi_{i} = \begin{cases} \xi_{b} & i > 1 \\ \xi_{s} & i = 1, \text{ before chemisorption} \\ \xi_{c} & i = 1, \text{ after chemisorption.} \end{cases}$$
(3)

In (3),

$$\xi_i = \frac{\Delta^2 X_b (1 - X_b) F_i(Z_1)}{1 - \Delta (1 - 2X_b) F_i(Z_1)} \qquad i = b, s, c$$
(4)

where $F_b(Z_1)$ is a diagonal element of the GF for the infinite DBA under the virtualcrystal approximation, and $F_s(Z_1)$ ($F_c(Z_1)$) is that of the surface GF at site 1 before (after) chemisorption. They can be determined by the following:

$$F_{\rm b}(Z_1) = 1/\left(2T\sqrt{Z_1^2 - 1}\right) \tag{5}$$

$$F_{\rm s}(Z_{\rm 1}) = \left[F_{\rm s0}^{-1}(Z_{\rm 1}) - (X_{\rm s} - X_{\rm b})\Delta\right]^{-1} \tag{6}$$

$$F_{\rm c}(Z_1) = \left[F_{\rm s}^{-1}(Z_1) - \gamma^2 G_{\rm a}\right]^{-1} \tag{7}$$

where

$$Z_{1} = (E + i0^{+} - \alpha_{b})/2T$$
(8)

$$F_{s0}(Z_1) = \left(Z_1 - \sqrt{Z_1^2 - 1}\right)/T.$$
(9)

The effective GF of the effective adsorbate is defined by

$$G_{\rm a} = \left(E - E_{\rm eff} + i0^+\right)^{-1} \tag{10}$$

where $E_{\rm eff}$ is the effective level of the effective adsorbate attached to the surface atom of the substrate by a bond of energy γ which can be represented by

$$\gamma = X_{\rm c} \gamma_{\rm A} + (1 - X_{\rm c}) \gamma_{\rm B}. \tag{11}$$

Before chemisorption the effective Hamiltonian for the semi-DBA is

$$H_{\rm eff} = H_{\rm v} + \sum_{i=1}^{\infty} \xi_i |i\rangle \langle i|$$
(12)

and, therefore, the effective surface GF is

$$G_{\rm s} = \left[F_{\rm s0}^{-1}(Z_2) - (\xi_{\rm a} - \xi_{\rm b}) - (X_{\rm s} - X_{\rm b})\Delta\right]^{-1}$$
(13)

where

$$Z_2 = \left(E + \mathrm{i}0^+ - \alpha_b - \xi_b\right)/2T. \tag{14}$$

After chemisorption the effective Hamiltonian of the chemisorption system is

$$H_{\text{eff}}^{c} = E_{\text{eff}} |a\rangle \langle a| + H_{\text{eff}} + \left[(X_{c} - X_{s})\Delta + (\xi_{c} - \xi_{s}) \right] |1\rangle \langle 1| + \gamma (|a\rangle \langle 1| + |1\rangle \langle a|).$$
(15)

According to the chemisorption theory of Einstein and Schrieffer [4], the change in the density of states caused by chemisorption is

$$\Delta \rho(E) = -(1/\pi) \operatorname{Im} \left(\partial/\partial E \right) \left[\ln \det \left(1 - \mathbf{G}^0 \mathbf{V} \right) \right]$$
(16)

where

$$\mathbf{G}^{0} = \begin{bmatrix} G_{\mathbf{a}} & 0\\ 0 & G_{\mathbf{s}} \end{bmatrix} \tag{17}$$

$$\mathbf{V} = \begin{bmatrix} 0 & \gamma \\ \gamma & (X_{\rm c} - X_{\rm s})\Delta + (\xi_{\rm c} - \xi_{\rm s}) \end{bmatrix}.$$
(18)

The chemisorption energy can be written as

$$\Delta E = 2 \int_{-\infty}^{E_{\rm F}} (E - E_{\rm F}) \ \Delta \rho(E) \ dE \tag{19}$$

where $E_{\rm F}$ is the Fermi level. A direct calculation of this integral is rather cumbersome (the integrand can have sharp peaks due to the presence of resonance). The technique of complex-energy-plane integration [5] is, therefore, adopted to calculate the chemisorption energy, i.e.,

$$\Delta E = \frac{2}{\pi} \int_0^\infty \operatorname{Re} f(Z) \, \mathrm{d}y \tag{20}$$

where

$$f(Z) = (Z - E_{\rm F})(\partial/\partial Z) \ln\{1 - [(X_{\rm c} - X_{\rm s})\Delta + (\xi_{\rm c} - \xi_{\rm s})]G_{\rm s}(Z) - \gamma^2 G_{\rm a}(Z)G_{\rm s}(Z)\}.$$
(21)

In (20) and (21),

$$Z = E_{\rm F} + iy \tag{22}$$

where the y are real numbers.

Table 1. Parameters for pure metals; Ni, Cu; all energies are in eV.

	Parameter			
Element	€a(B)	E_{F}	γ _{A(B)} /Ο	$\gamma_{A(B)}/CO$
Ni	-6.260	-4.500	4.217	2.763
Cu	-7.370	-4.460	4.725	3.320

Table 2. Surface concentrations X_s , X_c/O and X_c/CO versus bulk Ni concentration X_b for segregated Ni-Cu alloy.

$\overline{X_{\mathfrak{b}}}$	Xs	X _c /O	X_{c} /CO
0.0	0.00000	0.00000	0.00000
0.1	0.00009	0.18314	0.04314
0.2	0.00020	0.33530	0.09209
0.3	0.00035	0.46374	0.14813
0.4	0.00054	0.57359	0.21290
0.5	0.00081	0.66863	0.28863
0.6	0.00122	0.75165	0.37834
0.7	0.00189	0.82481	0.48632
0.8	0.00324	0.88975	0.61875
0.9	0.00725	0.94781	0.78502
1.0	1.00000	1.00000	1.00000

Utilizing the pure-substrate parameters found in table 1, calculations of the chemisorption energies of the O/Ni-Cu and CO/Ni-Cu systems have been performed over the full range of bulk concentrations (X_b) . The values of the effective energy $E_{\rm eff}$ of O (CO) and the adsorbate coverage θ are chosen to be -7.5 eV (-7.7 eV) and 0.5, respectively. The surface component concentration X_s (X_c) is calculated, employing the expression for the surface concentration of an alloy $A_x B_{1-x}$ before





Figure 1. Chemisorption energy ΔE for O/Ni-Cu versus bulk Ni concentration X_b , taking into consideration the change of surface segregation due to chemisorption.

Figure 2. Chemisorption energy ΔE for CO/Ni– Cu versus bulk Ni concentration X_b , taking into consideration the change of surface segregation due to chemisorption.

(after) chemisorption as given in [6], and the results are shown in table 2. Unlike in the case of atomic hydrogen adsorption [7], the change of the surface component concentration (see table 2) due to the chemisorption for the systems of O/Ni-Cu and CO/Ni-Cu cannot be neglected, and this drastically affects the chemisorption energy. In figure 1, the graph has a steep slope. This means that the chemisorption for the O/Ni-Cu system strongly constrains surface segregation, resulting in an enriched Ni concentration in the surface layer for all compositions and chemisorption properties more like the behaviour of O/Ni than that of O/Cu. Compared with the case in which the mutual influence of the chemisorption and surface segregation [8] need not be considered, the result is that the chemisorption energy decrease further and the chemisorption is more stable. In figure 2, the curve's shape resembles that of curve c in figure 2 of [1], which shows that the results obtained by using the ATA are as good as those obtained by using the CPA, but now a self-consistent calculation has been omitted. For the CO/Ni-Cu system, the chemisorption property is similar to that of the O/Ni-Cu system, i.e. they can all constrain surface segregation and strengthen the chemisorption. Here, we see again the result of the mutual influence of chemisorption and surface segregation.

References

- [1] Zhang H 1992 Surf. Sci. 269/270 331
- [2] Ueba H and Ichimura S 1979 Phys. Status Solidi b 92 307
- [3] Berk N F 1975 Surf. Sci. 48 289
- [4] Einstein T L and Schrieffer J R 1979 Phys. Rev. B 7 3629
- [5] Dreysse H and Riedinger R 1983 Phys. Rev. B 28 5669
- [6] Tomanek D, Mukherjee S, Kumar V and Bennemann K H 1982 Surf. Sci. 114 11
- [7] Sulston K W, Davison S G and Lui W K 1986 Phys. Rev. B 33 2263
- [8] Yang Z X and Zhang T 1991 Acta Phys. Sin. 40 269